NOT RECOMMENDED FOR NEW DESIGN
USE DGD2104M

Lead-free Green

DGD2104A

HALF-BRIDGE GATE DRIVER IN SO-8

Description

The DGD2104A is a high-voltage, high-speed gate driver capable of driving N-Channel MOSFETs and IGBTs in a half bridge configuration. High-voltage processing techniques enable the DGD2104A's high-side to switch to 600V in a bootstrap operation.

The DGD2104A logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction. The DGD2104A has a fixed internal deadtime of 520ns (typical).

The DGD2104A is offered in the SO-8 (Type TH) package and operates over an extended -40°C to +125°C temperature range.

Features

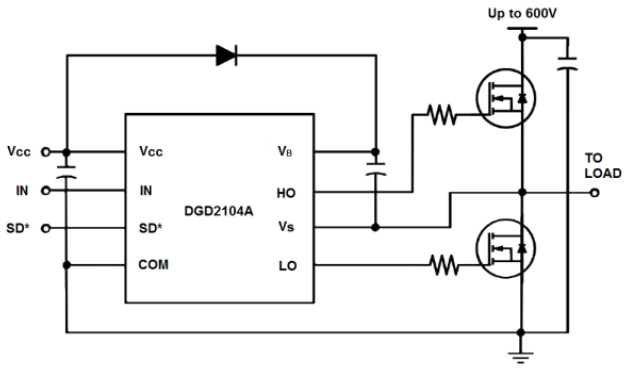
- Floating High-Side Driver in Bootstrap Operation to 600V
- Drives Two N-Channel MOSFETs or IGBTs in a Half Bridge Configuration
- 210mA Source / 360mA Sink Output Current Capability
- Outputs Tolerant to Negative Transients
- Internal Dead Time of 520ns to Protect MOSFETs
- Wide Low Side Gate Driver Supply Voltage: 10V to 20V
- Logic Input (IN and SD*) 3.3V Capability
- Schmitt Triggered Logic Inputs
- Undervoltage Lockout for V_{CC} (Logic and Low Side Supply)
- Extended Temperature Range: -40°C to +125°C
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony free. "Green" Device (Note 3)**

Applications

- DC-DC Converters
- DC-AC Inverters
- AC-DC Power Supplies
- Motor Controls
- Class D Power Amplifiers

Mechanical Data

- Case: SO-8 (Type TH)
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.075 grams (Approximate)



Typical Configuration

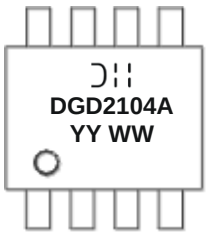
SO-8 (Type TH)
Top View

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DGD2104AS8-13	DGD2104A	13	12	2,500

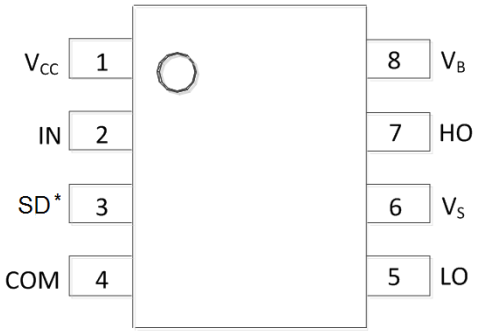
Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



= Manufacturer's Marking
DGD2104A = Product Type Marking Code
YY = Year (ex: 16 = 2016)
WW = Week (01 to 53)

Pin Diagrams

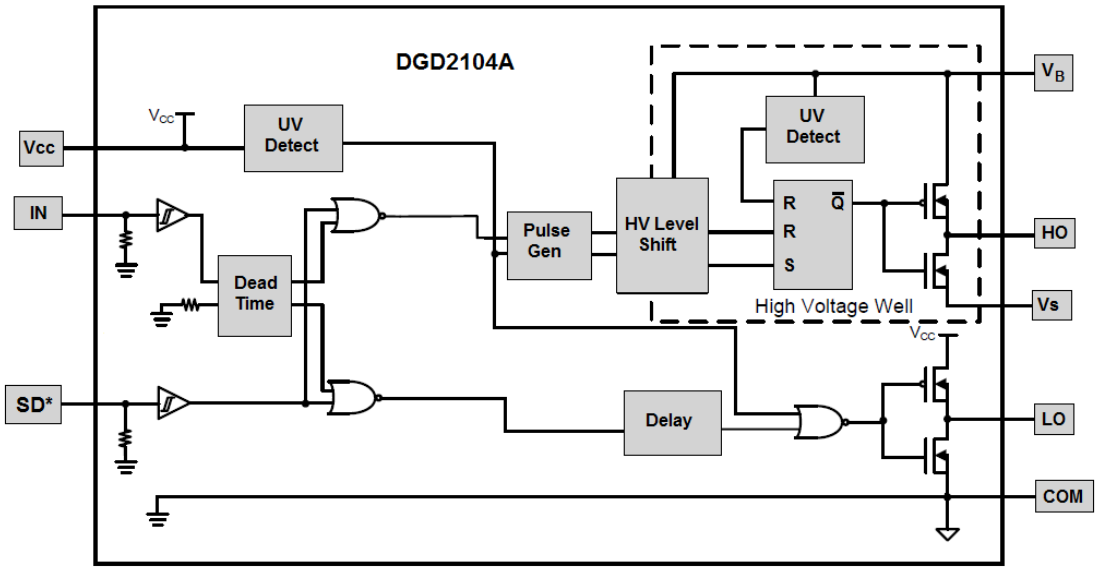


Top View: SO-8 (Type TH)

Pin Descriptions

Pin Number	Pin Name	Function
1	V_{CC}	Logic and Low Side Supply
2	IN	Logic Input for High-Side and Low-Side Gate Driver Outputs (HO and LO), in Phase with HO
3	SD*	Logic Input for Shutdown, Enabled Low
4	COM	Low-Side and Logic Return
5	LO	Low-Side Gate Drive Output
6	V_S	High-Side Floating Supply Return
7	HO	High-Side Gate Drive Output
8	V_B	High-Side Floating Supply

Functional Block Diagram



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Supply Voltage	V_B	-0.3 to +624	V
High-Side Floating Supply Offset Voltage	V_S	V_B-24 to V_B+0.3	V
High-Side Floating Output Voltage	V_{HO}	V_S-0.3 to V_B+0.3	V
Offset Supply Voltage Transient	dV_S / dt	50	V/ns
Low-Side Fixed Supply Voltage	V_{CC}	-0.3 to +24	V
Low-Side Output Voltage	V_{LO}	-0.3 to V_{CC}+0.3	V
Logic Input Voltage (IN and SD*)	V_{IN}	-0.3 to V_{CC}+0.3	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	P_D	0.625	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	200	°C/W
Operating Temperature	T_J	+150	°C
Lead Temperature (Soldering, 10s)	T_L	+300	
Storage Temperature Range	T_{STG}	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High Side Floating Supply Absolute Voltage	V_B	V_S + 10	V_S + 20	V
High Side Floating Supply Offset Voltage	V_S	(Note 6)	600	V
High Side Floating Output Voltage	V_{HO}	V_S	V_B	V
Low Side Fixed Supply Voltage	V_{CC}	10	20	V
Low Side Output Voltage	V_{LO}	0	V_{CC}	V
Logic Input Voltage (IN and SD*)	V_{IN}	0	5	V
Ambient Temperature	T_A	-40	+125	°C

Note: 6. Logic operation for V_S of -5V to +600V. Logic state held for V_S of -5V to -V_{BS}.

DC Electrical Characteristics (V_{BIAS} (V_{CC}, V_{BS}) = 15V, @T_A = +25°C, unless otherwise specified.) (Note 7)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Logic "1" (IN) & Logic "0" (SD*) Input Voltage	V_{IH}	2.5	–	–	V	V_{CC} = 10V to 20V
Logic "0" (IN) & Logic "1" (SD*) Input Voltage	V_{IL}	–	–	0.8	V	V_{CC} = 10V to 20V
High Level Output Voltage, V_{BIAS} - V_O	V_{OH}	–	0.05	0.2	V	I_O = 2mA
Low Level Output Voltage, V_O	V_{OL}	–	0.02	0.1	V	I_O = 2mA
Offset Supply Leakage Current	I_{LK}	–	–	50	µA	V_B = V_S = 600V
Quiescent V_{BS} Supply Current	I_{BSQ}	–	30	55	µA	V_{IN} = 0V or 5V
Quiescent V_{CC} Supply Current	I_{CCQ}	–	370	500	µA	V_{IN} = 0V or 5V
Logic "1" Input Bias Current	I_{IN+}	–	3	10	µA	V_{IN} = 5V, SD* = 0V
Logic "0" Input Bias Current	I_{IN-}	–	–	5	µA	V_{IN} = 0V, SD* = 5V
V_{CC} Supply Under-Voltage Positive Going Threshold	V_{CCUV+}	8.0	8.9	9.8	V	–
V_{CC} Supply Under-Voltage Negative Going Threshold	V_{CCUV-}	7.4	8.2	9.0	V	–
Output High Short Circuit Pulsed Current	I_{O+}	130	210	–	mA	V_O = 0V, PW ≤ 10µs
Output Low Short Circuit Pulsed Current	I_{O-}	270	360	–	mA	V_O = 15V, PW ≤ 10µs

Note: 7. The V_{IN} and I_{IN} parameters are applicable to the two logic input pins: IN and SD*. The V_O and I_O parameters are applicable to the respective output pins: HO and LO.

AC Electrical Characteristics (V_{BIAS} (V_{CC}, V_{BS}) = 15V, C_L = 1000pF, @T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Turn-On Propagation Delay	t_{ON}	–	680	820	ns	V_S = 0V
Turn-Off Propagation Delay	t_{OFF}	–	150	220	ns	V_S = 600V
Shutdown Propagation Delay	t_{SD}	–	160	220	ns	–
Delay Matching, HO & LO Turn-On / Turn-Off	t_{DM}	–	–	60	ns	–
Turn-On Rise Time	t_R	–	100	170	ns	V_S = 0V
Turn-Off Fall Time	t_F	–	50	60	ns	V_S = 0V
Deadtime: $t_{DT\ LO-HO}$ & $t_{DT\ HO-LO}$	t_{DT}	400	520	650	ns	–

Timing Waveforms

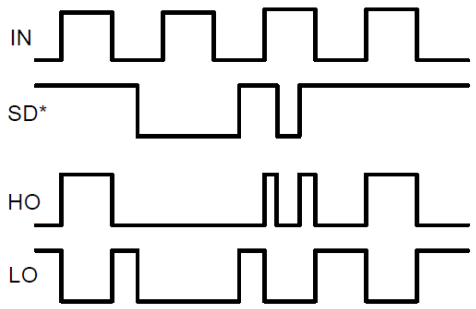


Figure 1. Input / Output Timing Diagram

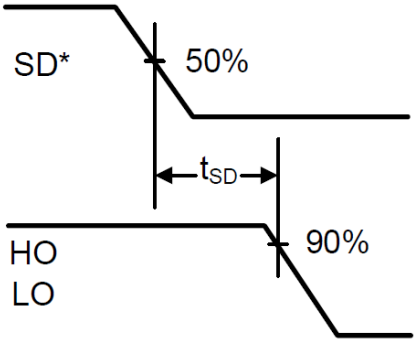
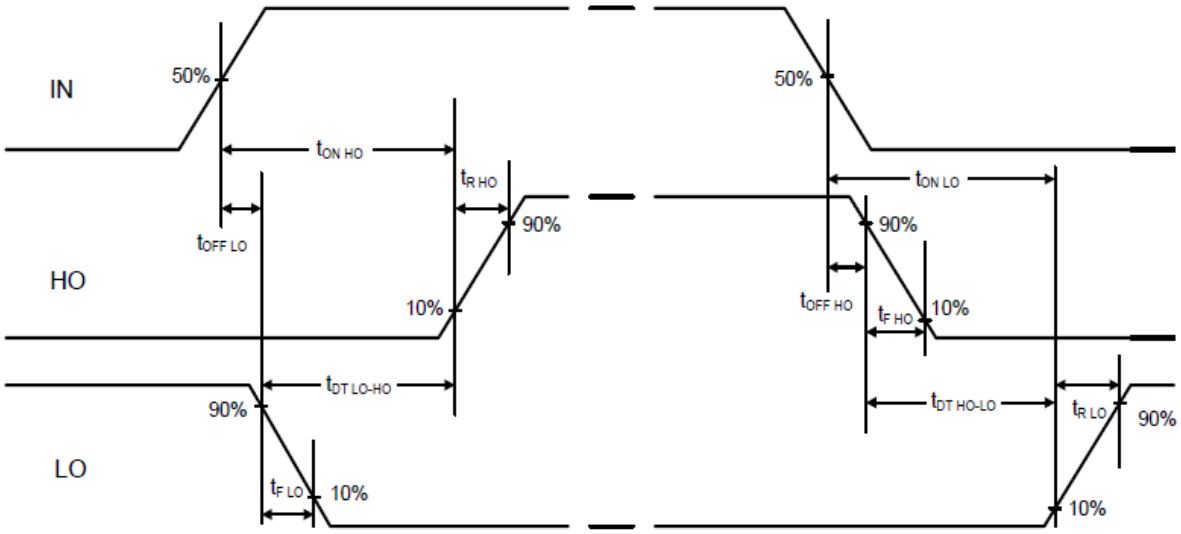


Figure 2. Shutdown Waveform Definition



Deadtime $t_{DT\ LO-HO} = t_{ON\ HO} - t_{OFF\ LO}$
$t_{DT\ HO-LO} = t_{ON\ LO} - t_{OFF\ HO}$

Deadtime matching
$t_{MDT} = t_{DT\ LO-HO} - t_{DT\ HO-LO}$

Delay matching
$t_{DM\ OFF} = t_{OFF\ LO} - t_{OFF\ HO}$
$t_{DM\ ON} = t_{ON\ LO} - t_{ON\ HO}$

Figure 3. Switching Time Waveform Definitions

Typical Performance Characteristics (@T_A = +25°C, unless otherwise specified.)

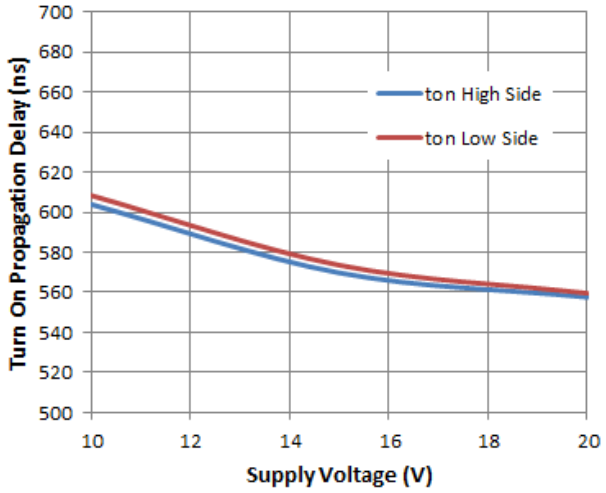


Figure 4. Turn-on Propagation Delay vs. Supply Voltage

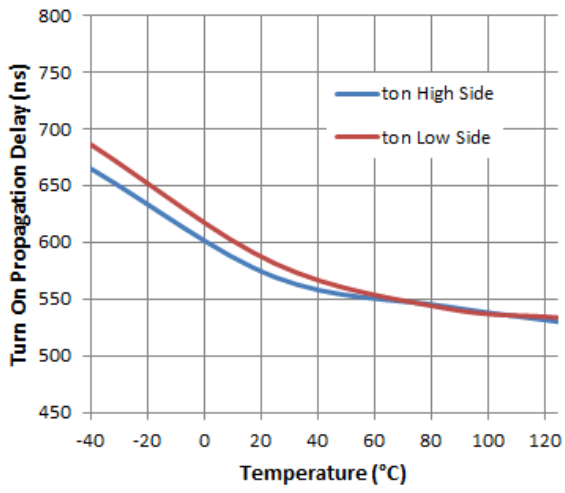


Figure 5. Turn-on Propagation Delay vs. Temperature

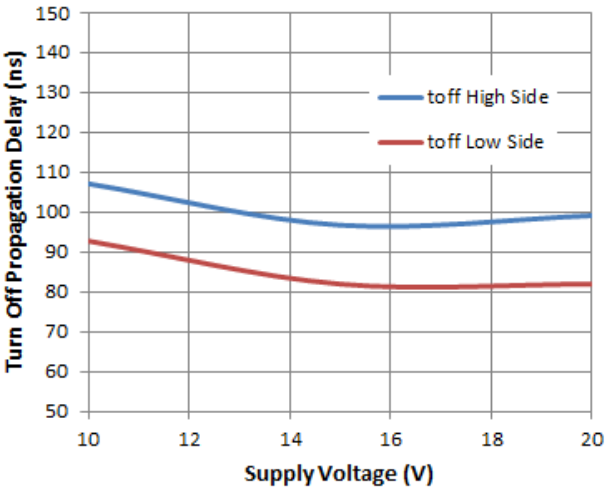


Figure 6. Turn-off Propagation Delay vs. Supply Voltage

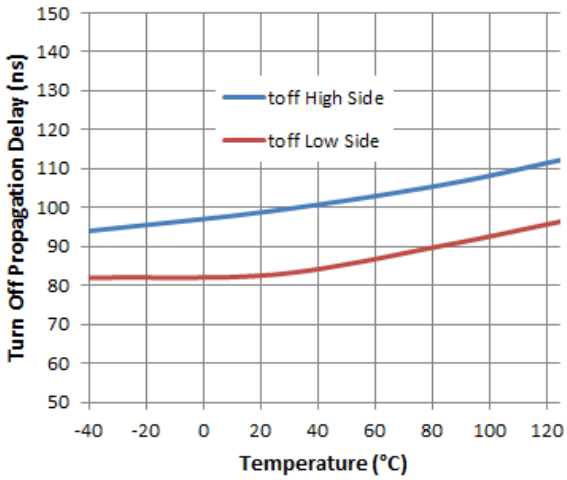


Figure 7. Turn-off Propagation Delay vs. Temperature

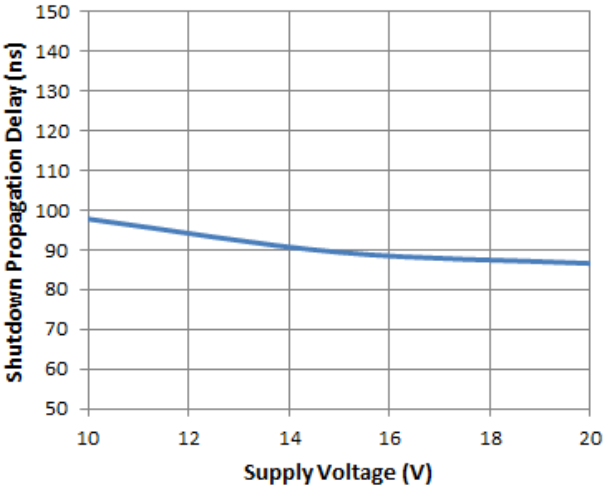


Figure 8. Shutdown Propagation Delay vs. Supply Voltage

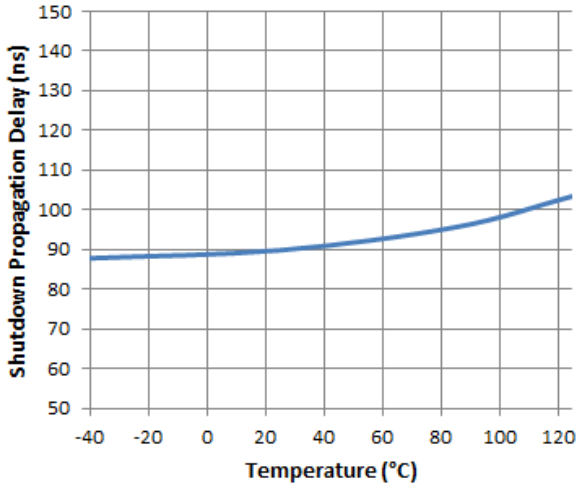


Figure 9. Shutdown Propagation Delay vs. Temperature

Typical Performance Characteristics (Cont.)

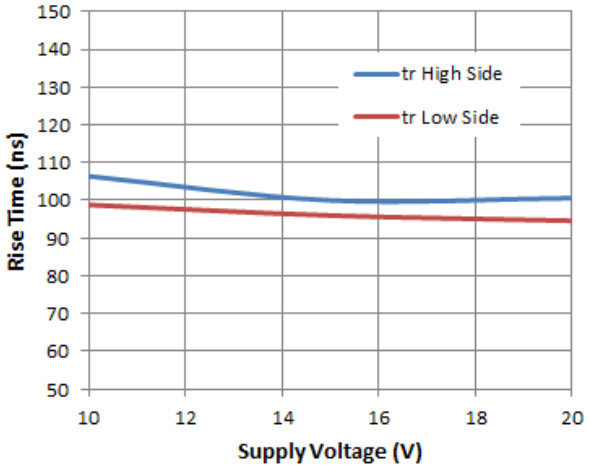


Figure 10. Rise Time vs. Supply Voltage

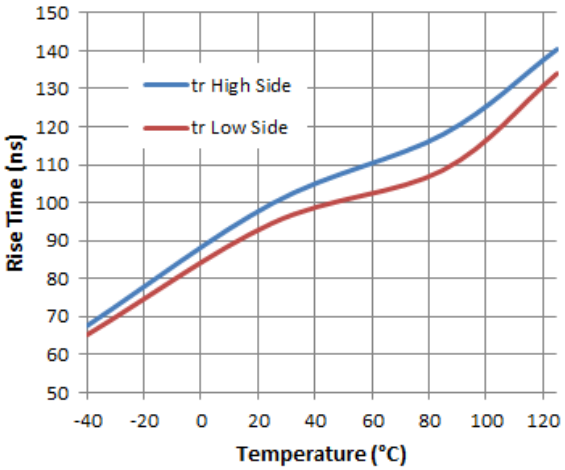


Figure 11. Rise Time vs. Temperature

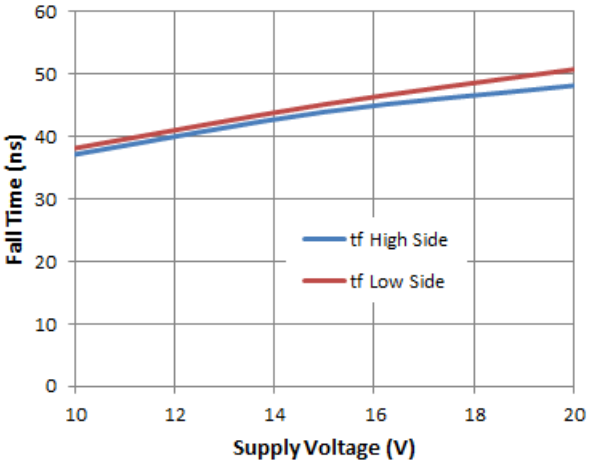


Figure 12. Fall Time vs. Supply Voltage

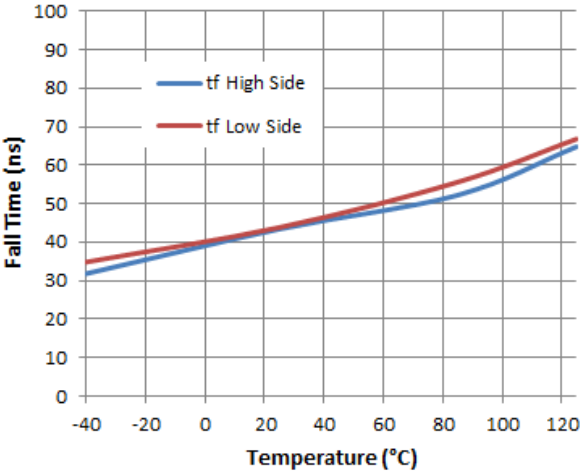


Figure 13. Fall Time vs. Temperature

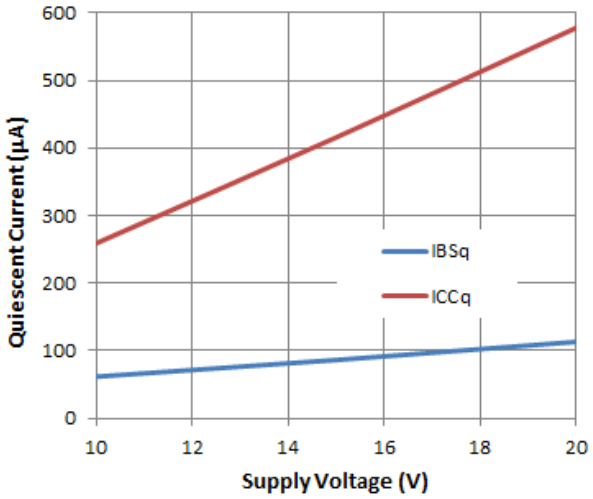


Figure 14. Quiescent Current vs. Supply Voltage

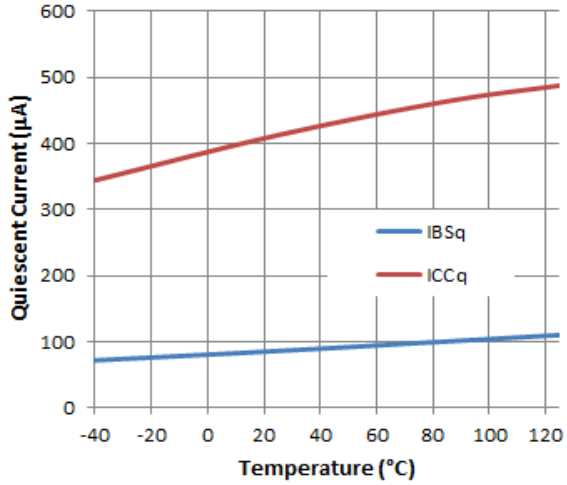


Figure 15. Quiescent Current vs. Temperature

Typical Performance Characteristics (Cont.)

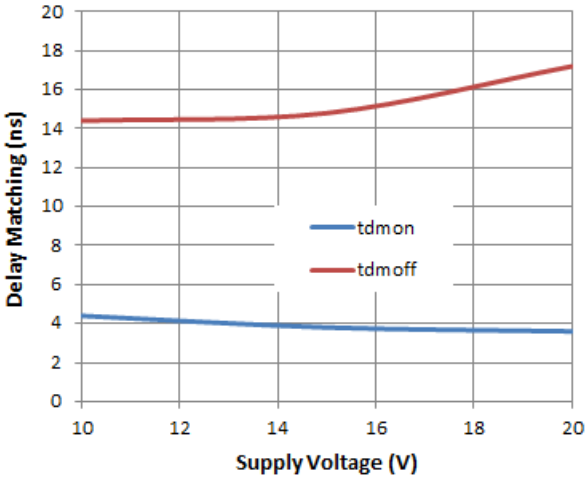


Figure 16. Delay Matching vs. Supply Voltage

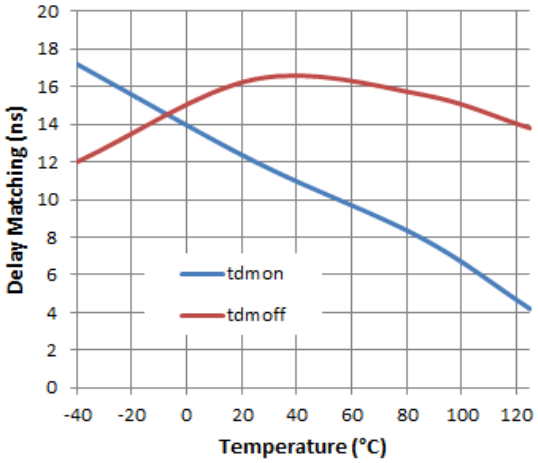


Figure 17. Delay Matching vs. Temperature

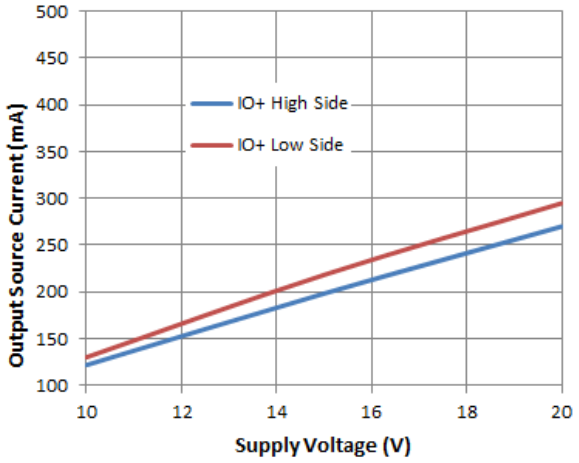


Figure 18. Output Source Current vs. Supply Voltage

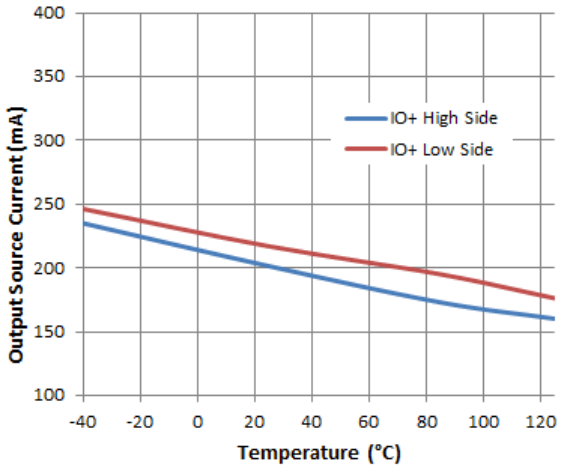


Figure 19. Output Source Current vs. Temperature

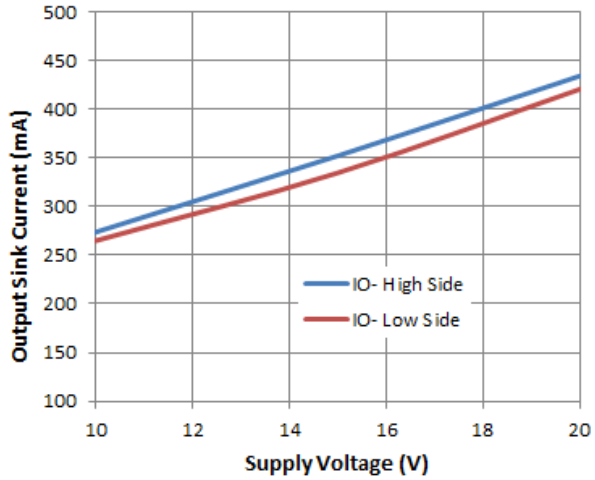


Figure 20. Output Sink Current vs. Supply Voltage

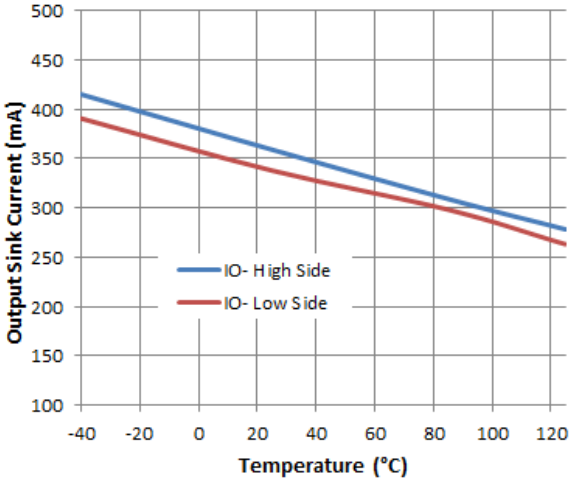


Figure 21. Output Sink Current vs. Temperature

Typical Performance Characteristics (Cont.)

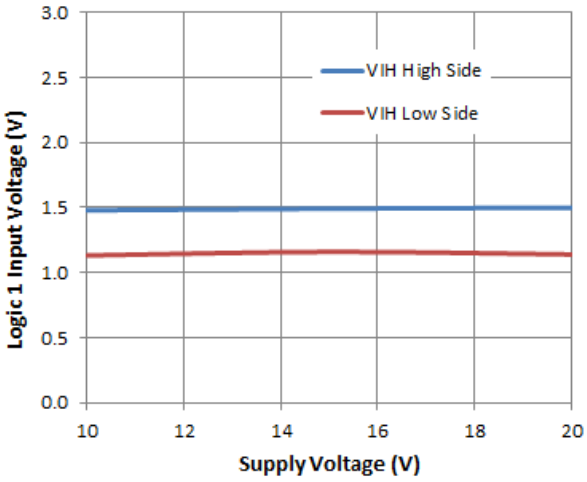


Figure 22. Logic 1 Input Voltage vs. Supply Voltage

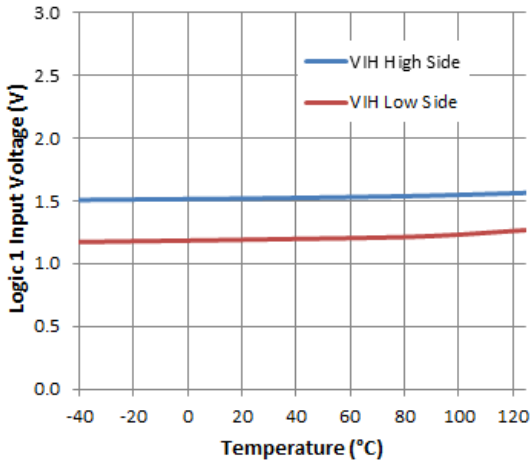


Figure 23. Logic 1 Input Voltage vs. Temperature

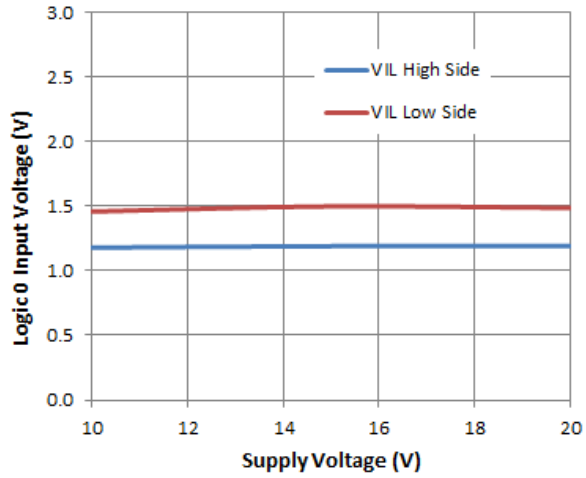


Figure 24. Logic 0 Input Voltage vs. Supply Voltage

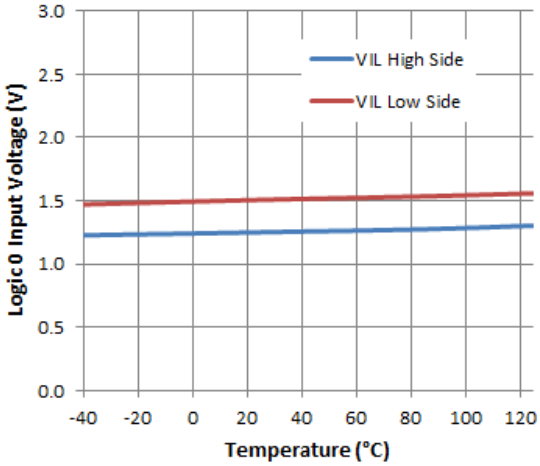


Figure 25. Logic 0 Input Voltage vs. Temperature

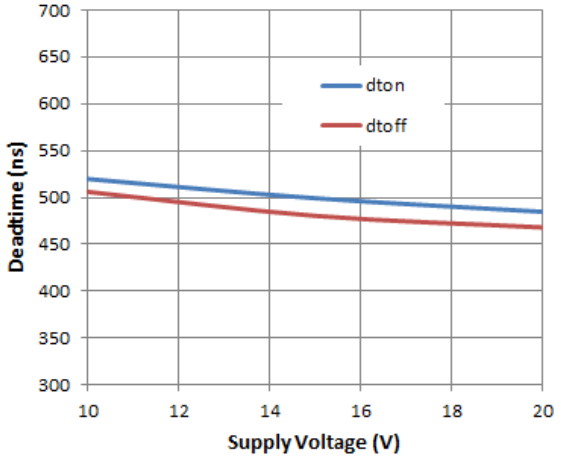


Figure 26. Deadtime vs. Supply Voltage

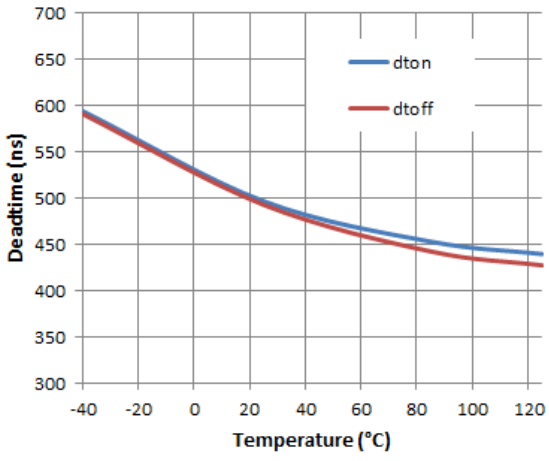


Figure 27. Deadtime vs. Temperature

Typical Performance Characteristics (Cont.)

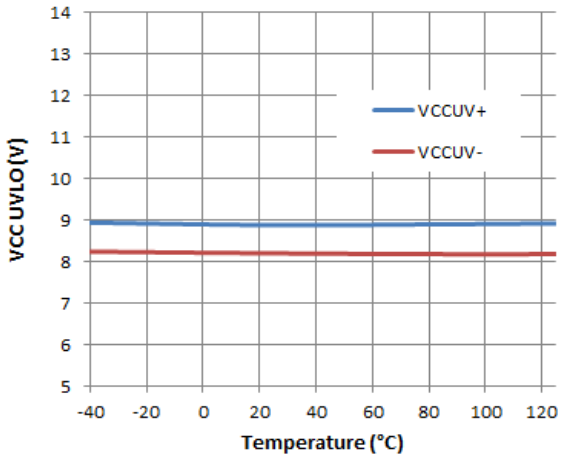


Figure 28. VCC UVLO vs. Temperature

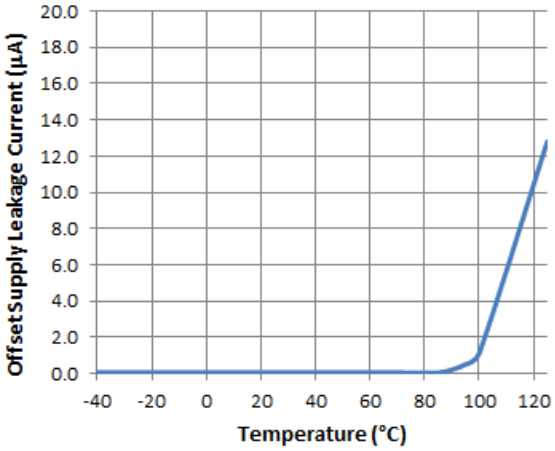
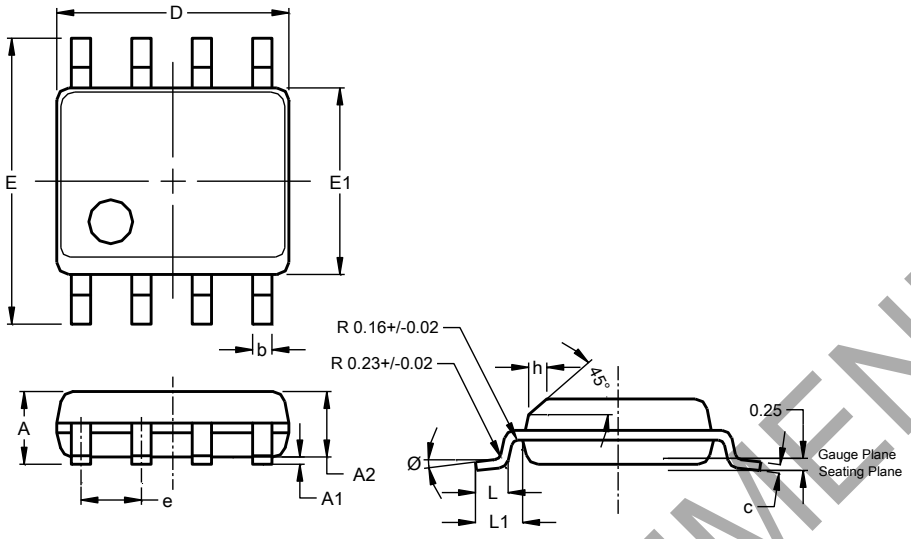


Figure 29. Offset Supply Leakage Current vs. Temperature

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8 (Type TH)

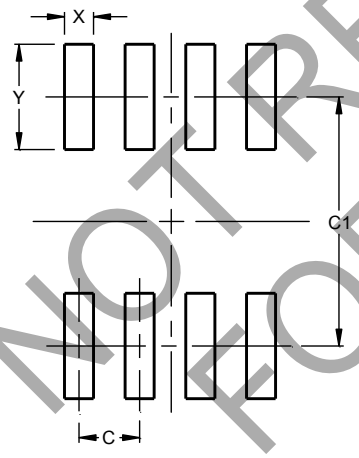


SO-8 (Type TH)			
Dim	**Min**	**Max**	**Typ**
A	1.35	1.75	--
A1	0.10	0.25	--
A2	--	--	1.45
b	0.35	0.51	--
c	0.190	0.248	--
D	4.80	5.00	4.90
E	5.80	6.20	6.00
E1	3.80	4.00	3.90
e	--	--	1.27
h	0.25	0.50	--
L	0.41	1.27	--
L1	--	--	1.04
Ø	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8 (Type TH)



Dimensions	Value (in mm)
C	1.27
C1	5.20
X	0.60
Y	2.20

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

www.diodes.com

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Gate Drivers ***category:***

Click to view products by Diodes Incorporated ***manufacturer:***

Other Similar products are found below :

00053P0231 56956 57.404.7355.5 LT4936 57.904.0755.0 5882900001 00600P0005 00-9050-LRPP 00-9090-RDPP 5951900000 01-1003W-10/32-15 0131700000 00-2240 LTP70N06 LVP640 5J0-1000LG-SIL LY1D-2-5S-AC120 LY2-US-AC240 LY3-UA-DC24 00576P0020 00600P0010 LZN4-UA-DC12 LZNQ2M-US-DC5 LZNQ2-US-DC12 LZP40N10 00-8196-RDPP 00-8274-RDPP 00-8275-RDNP 00-8722-RDPP 00-8728-WHPP 00-8869-RDPP 00-9051-RDPP 00-9091-LRPP 00-9291-RDPP 0207100000 0207400000 01312 0134220000 60713816 M15730061 61161-90 61278-0020 6131-204-23149P 6131-205-17149P 6131-209-15149P 6131-218-17149P 6131-220-21149P 6131-260-2358P 6131-265-11149P CS1HCPU63